

## APGF1011SEEPBVGC-TT

1 x 1 x 0.2 mm Full-Color Surface Mount LED



## **DESCRIPTIONS**

- The Green source color devices are made with InGaN on SiC substrate Light Emitting Diode
- The Blue source color devices are made with InGaN on SiC substrate Light Emitting Diode
- The Hyper-Red source color devices are made with AlGaInP on GaAs substrate Light Emitting Diode
- · Electrostatic discharge and power surge could damage the LEDs
- It is recommended to use a wrist band or anti-electrostatic glove when handling the LEDs
- · All devices, equipments and machineries must be electrically grounded

## **FEATURES**

- 1.0 mm x 1.0 mm SMD LED, 0.2 mm thickness
- · Low power consumption
- Package: 4000 pcs / reel
- Moisture sensitivity level: 3
- · Halogen-free
- · RoHS compliant

## **APPLICATIONS**

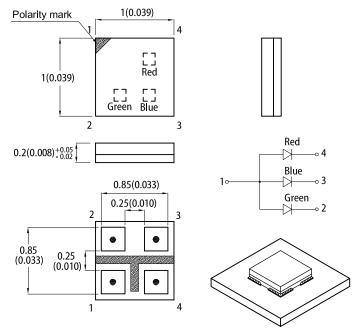
- Backlight
- Status indicator
- Home and smart appliances
- · Wearable and portable devices
- · Healthcare applications

## **ATTENTION**

Observe precautions for handling Electrostatic discharge sensitive devices

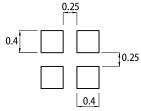


## PACKAGE DIMENSIONS



## RECOMMENDED SOLDERING PATTERN

(units: mm; tolerance: ± 0.1)



Mask open area ratio: 80% Mask thickness: 80~100um

- 17. All dimensions are in millimeters (inches).
  2. Tolerance is ±0.1(0.004") unless otherwise noted.
  3. The specifications, characteristics and technical data described in the datasheet are subject to change without prior notice.
- The device has a single mounting surface. The device must be mounted according to the specifications

### **SELECTION GUIDE**

Part Number	Emitting Color (Material)	Lens Type	Iv (mcd) @ 5mA [2]		Viewing Angle [1]
			Min.	Тур.	201/2
APGF1011SEEPBVGC-TT	■ Green (InGaN)	Water Clear	50	80	
	■ Blue (InGaN)		10	23	150°
	Hyper Red (AlGalnP)		15	30	

Notes.
1. 61/2 is the angle from optical centerline where the luminous intensity is 1/2 of the optical peak value.
2. Luminous intensity / luminous flux: +/-15%.

3. Luminous intensity value is traceable to CIE127-2007 standards.



## ELECTRICAL / OPTICAL CHARACTERISTICS at T<sub>A</sub>=25°C

Parameter	Comple el	Funistina Calan	Value		Unit	
Parameter	Symbol	Emitting Color	Тур.	Max.	Onit	
Wavelength at Peak Emission I <sub>F</sub> = 5mA	$\lambda_{peak}$	Green Blue Hyper Red	518 461 - 632		nm	
Dominant Wavelength I <sub>F</sub> = 5mA	λ <sub>dom</sub> <sup>[1]</sup>	Green Blue Hyper Red	527 467 624	-	nm	
Spectral Bandwidth at 50% $\Phi$ REL MAX I <sub>F</sub> = 5mA	Δλ	Green Blue Hyper Red	35 22 20	-	nm	
Capacitance	С	Green Blue Hyper Red	100 110 25	-	pF	
Forward Voltage I <sub>F</sub> = 5mA	V <sub>F</sub> <sup>[2]</sup>	Green Blue Hyper Red	3 2.9 1.95	3.2 3.1 2.3	V	
Reverse Current (V <sub>R</sub> = 5V)	I <sub>R</sub>	Green Blue Hyper Red	-	50 50 10	μА	
Temperature Coefficient of $\lambda_{peak}$ $I_F$ = 5mA, -10°C $\leq$ T $\leq$ 85°C	TC <sub>λpeak</sub>	Green Blue Hyper Red	0.05 0.04 0.13	-	nm/°C	
Temperature Coefficient of $\lambda_{dom}$ $I_F$ = 5mA, -10°C $\leq$ T $\leq$ 85°C	TC <sub>Adom</sub>	Green Blue Hyper Red	0.03 0.03 0.06	-	nm/°C	
Temperature Coefficient of $V_F$ $I_F$ = 5mA, -10°C $\leq$ T $\leq$ 85°C	TC <sub>v</sub>	Green Blue Hyper Red	-3 -3 -1.9	-	mV/°C	

- 1. The dominant wavelength ( $\lambda$ d) above is the setup value of the sorting machine. (Tolerance  $\lambda$ d:  $\pm 1$ nm. ) 2. Forward voltage:  $\pm 0.1$ V.

- 3. Wavelength value is traceable to CIE127-2007 standards.
  4. Excess driving current and / or operating temperature higher than recommended conditions may result in severe light degradation or premature failure.

## ABSOLUTE MAXIMUM RATINGS at T<sub>A</sub>=25°C

Dayamatay	Symbol	Value			l lmi4
Parameter		Green	Blue	Hyper Red	Unit
Power Dissipation	P <sub>D</sub> [1]	35			mW
Reverse Voltage	V <sub>R</sub>	5	5	5	V
Junction Temperature	T <sub>j</sub>	125	125	115	°C
Operating Temperature	T <sub>op</sub>		°C		
Storage Temperature	T <sub>stg</sub>	-40 to +100			°C
DC Forward Current	I <sub>F</sub> <sup>[2]</sup>	10	10	10	mA
Peak Forward Current	I <sub>FM</sub> <sup>[3]</sup>	50	50	50	mA
Electrostatic Discharge Threshold (HBM)	-	1000	1000	3000	V
Thermal Resistance (Junction / Ambient)	R <sub>th JA</sub> [4]	580	430	640	°C/W
Thermal Resistance (Junction / Solder point)	R <sub>th JS</sub> <sup>[4]</sup>	440	330	500	°C/W

- Notes:

  1. Within 35mW when multiple chips are lightened

  2. The maximum ratings are valid for the case of lighting a single chip
  When two chips are lit at the same time, each chip should be driven at a current lower than 50% of the absolute maximum ratings
  When three chips are lit at the same time, each chip should be driven at a current lower than 30% of the absolute maximum ratings
  3. Duty Cycle ≤ 1/20, Pulse Width = 1ms.

  4. R<sub>th JA</sub>, R<sub>th JS</sub> Results from mounting on PC board FR4 (pad size ≥ 16 mm² per pad).

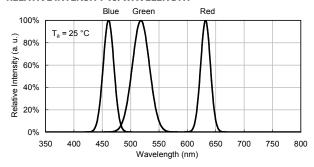
  5. Relative humidity levels maintained between 40% and 60% in production area are recommended to avoid the build-up of static electricity Ref JEDEC/JESD625-A and JEDEC/J-STD-033.



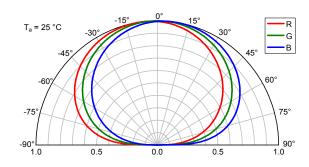


## **TECHNICAL DATA**

### **RELATIVE INTENSITY vs. WAVELENGTH**

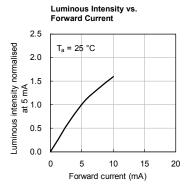


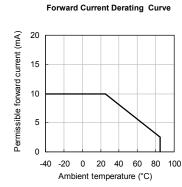
### **SPATIAL DISTRIBUTION**

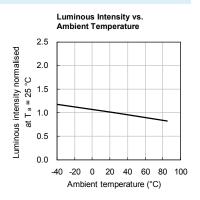


## **GREEN**

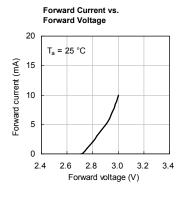
Forward Current vs. Forward Voltage 20 T<sub>a</sub> = 25 °C Forward current (mA) 15 10 5 0 2.2 2.4 2.6 2.8 3.0 3.2 3.4 Forward voltage (V)

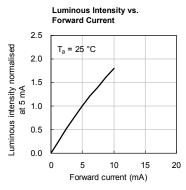


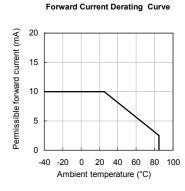


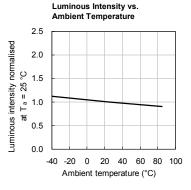


## **BLUE**



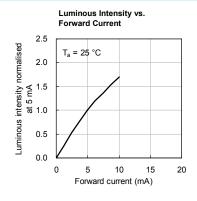


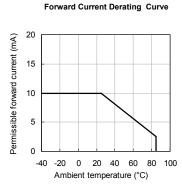


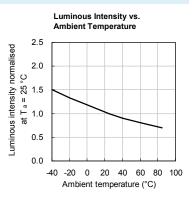


# **HYPER RED**

Forward Current vs. Forward Voltage 20  $T_a = 25 \, ^{\circ}C$ Forward current (mA) 15 10 0 2.1 1.8 1.9 2.0 Forward voltage (V)







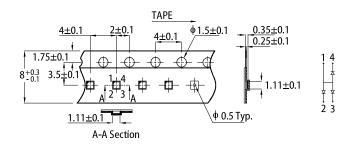


### **REFLOW SOLDERING PROFILE for LEAD-FREE SMD PROCESS**

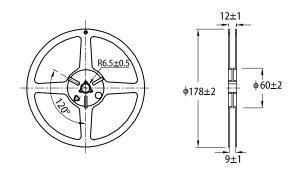
#### 300 above 255°C (°C) 260°C max. 30s max. 10s max. 250 3°C/s max. 6°C/s max. 200 150 Temperature pre-heating 100 150~200°C above 217°C 60~120s 60~150s 50 . 25℃ 150 200 250 0 50 100 300 (sec) Time -

- 1. Don't cause stress to the LEDs while it is exposed to high temperature.
  2. The maximum number of reflow soldering passes is 2 times.
  3. Reflow soldering is recommended. Other soldering methods are not recommended as they might cause damage to the product

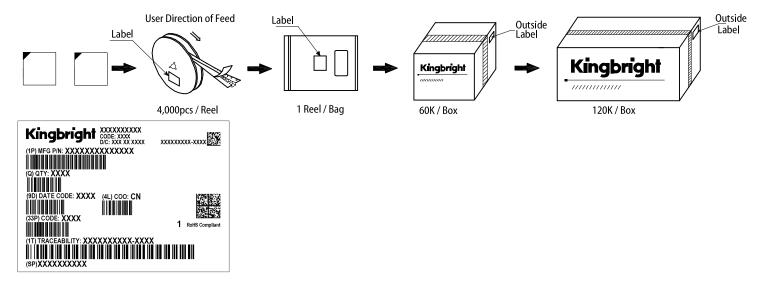
#### TAPE SPECIFICATIONS (units: mm)



#### **REEL DIMENSION** (units: mm)



## **PACKING & LABEL SPECIFICATIONS**



## **PRECAUTIONARY NOTES**

- The information included in this document reflects representative usage scenarios and is intended for technical reference only.
- The part number, type, and specifications mentioned in this document are subject to future change and improvement without notice. Before production usage customer should refer to the latest datasheet for the updated specifications.
- When using the products referenced in this document, please make sure the product is being operated within the environmental and electrical limits specified in the datasheet. If customer usage exceeds the specified limits, Kingbright will not be responsible for any subsequent issues.

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